



Main Features:

- Frequency Range: 24 to 41 GHz.
- Typical values: Psat 33 dBm, Gain 28 dB
- RF connectors (I/O): 2.4 mm Female
- Temperature monitoring
- Several mounting options
- Gold plated compact aluminum housing
- Hi-reliability and dedicated screening/
environmental tests available under request

ERZ-HPA-2400-4100-33

The ERZ-HPA-2400-4100-33 is a High Power Amplifier providing an output power of 33 dBm and a gain of 28 dB in the full Ka band. The compact size and modularity makes it ideal for a wide range of applications.

Typical applications:

- Industrial / Laboratory
- Satcom / Telecom
- Space / Aerospace / Military

Performance

Parameter	Value			Units
	Min	Typ	Max	
Frequency	24	-	41	GHz
Output Power (Psat)	30	33	33.5	dBm
Gain	20	26	40	dB
Noise Figure	-	-	-	dB
VSWR input	1.2:1	2.0:1	3.0:1	-
VSWR output	1.1:1	1.8:1	2.3:1	-
DC Voltage	10	20	28	V
Power Consumption	-	32	-	W
Connectors	2.4 mm Female IN/OUT			-

Specifications at case temperature of 25°C

Saturated Output Power

Figure 1-1 shows the saturated output power measured as a function of frequency at room temperature (25°C).

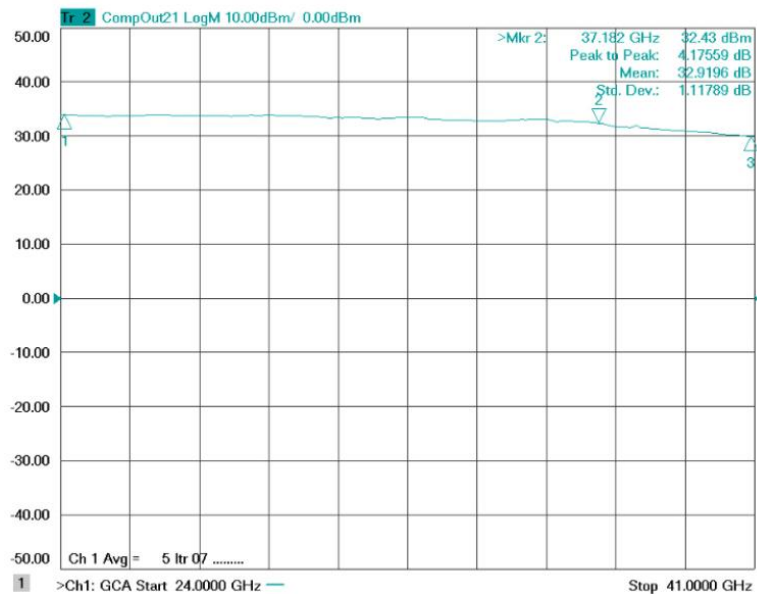


Figure 1-1: ERZ-HPA-2400-4100-33 Psat

Small Signal Gain

Figure 1-2 shows the small signal gain measured as a function of frequency at room temperature (25°C).

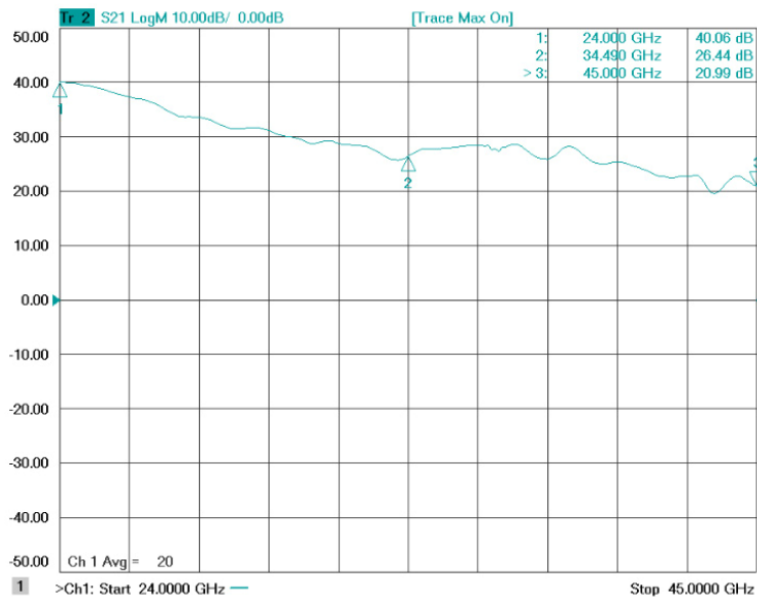


Figure 1-2: ERZ-HPA-2400-4100-33 Small Signal Gain

Input and Output Matching

Figure 1-4 and Figure 1-5 show input (S11) and output (S22) VSWR as a function of frequency at room temperature (25°C).

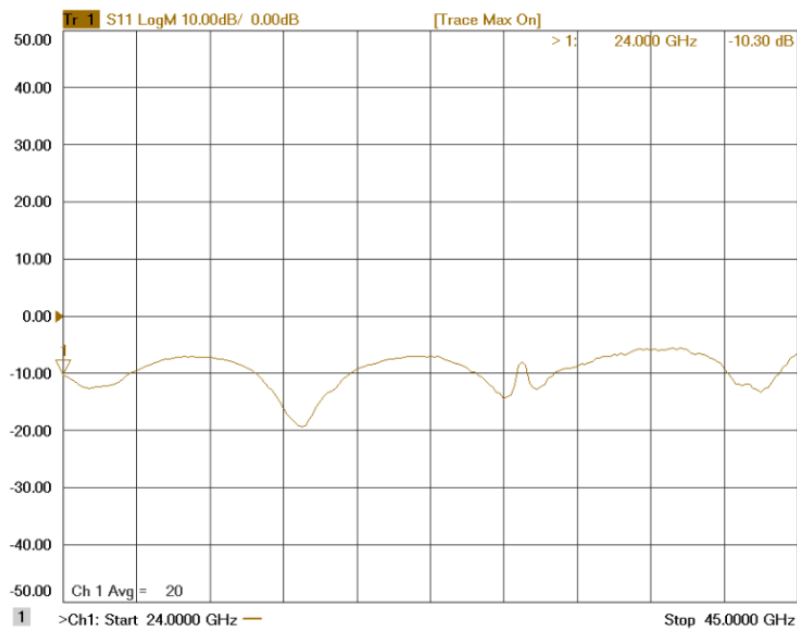


Figure 1-4: ERZ-HPA-2400-4100-33 Input Matching

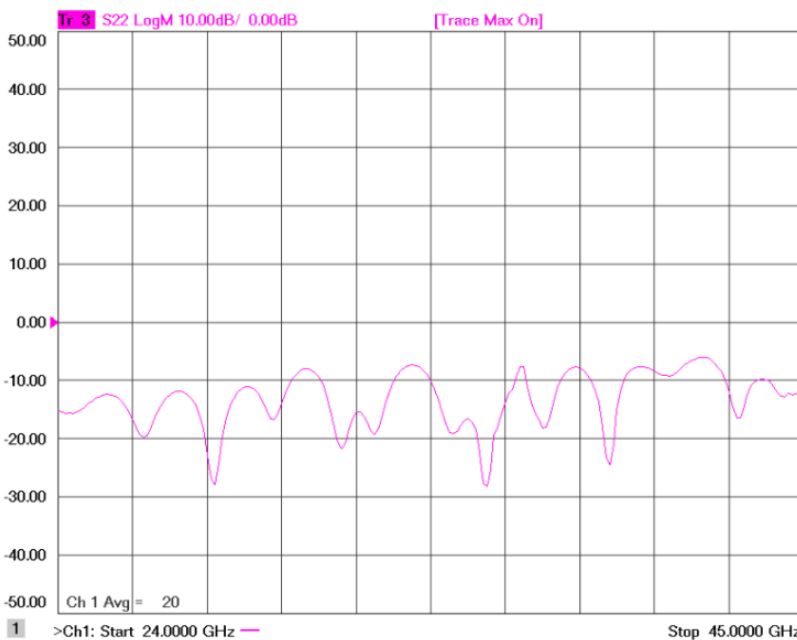


Figure 1-5: ERZ-HPA-2400-4100-33 Output Matching

Measurements Conditions

All measurements provided in this report were performed at the following conditions:

Condition	Value
Temperature	25°C ± 1°C
Humidity	70% ± 10%
DUT Warm up time	30 min
Test equipment warm up time	1 hour

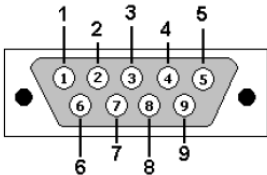
Absolute Maximum Ratings

Condition	Value
DC Voltage	+28 VDC
Maximum Input Power (CW)	20 dBm
Operation temperatura (at case)	-35°C to 65°C
Storage temperature	-45°C to 85°C

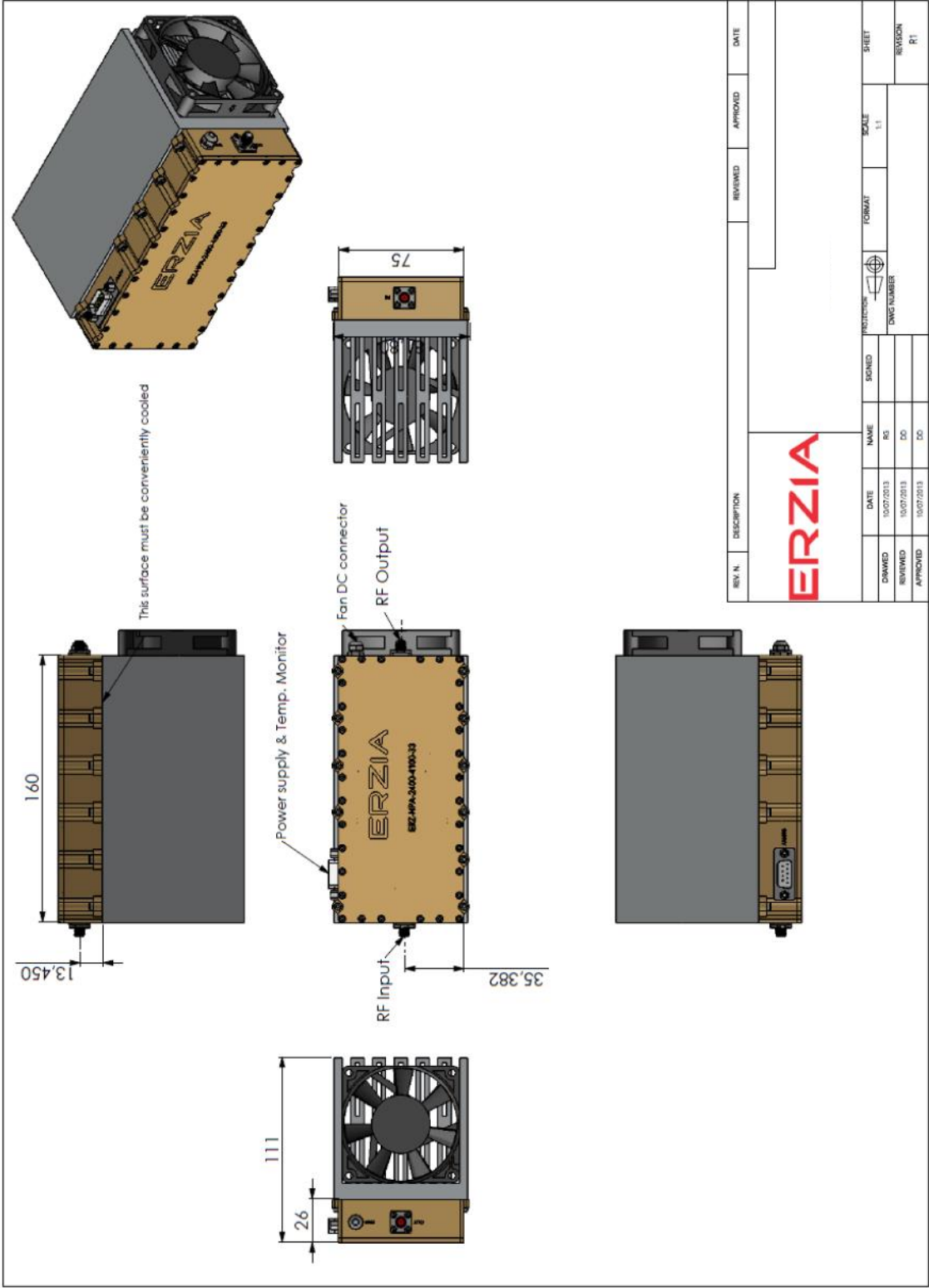
- Stress above these ratings may cause permanent damage to the device.
- It is final user responsibility to maintain the amplifier within the specified ranges.

Power Supply & Temperature monitoring

The amplifier can be supplied with input DC voltajes from 10 VDC to 28 VDC. Required DC current at startup is 2.5 higher than in stationary operation. The following table shows the pinout distribution for the amplifier's DB-9 male connector.

	
PIN	FUNCTION
1	+Vcc
2	+Vcc
3	+Vcc
4	Not Connected
5	Not Connected
6	GND
7	GND
8	GND
9	Temperature Monitor $V_{TMP} = 0.424 + \text{Temperature } (^{\circ}\text{C}) \times 0.00625$

Mechanics and Housing



Documentation and Test Reports

All modules are at least delivered with: Electrical Test Report, Certificate of Conformance, Certificate of Acceptance and Origin. Optionally, units can be environmentally tested (temperature, vibration...).

Option (HS): Heat Sink

A heat sink (HS) can be provided to allow the operation of Power Amplifiers. Please note that most power amplifiers need heat sink or appropriate heat dissipation strategy.

Space / Military Usage

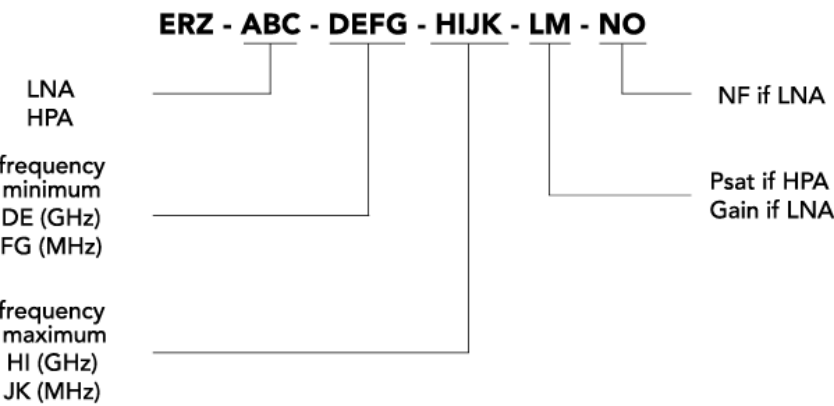
Most of ERZIA’s products are based on rad-hard technologies and can be manufactured and integrated according to MIL / ECSS or specific hi-rel standard-screening for space, aeronautics, military or specific hi-reliability usage.

Customization and Extended Performances

ERZIA can fully design or adapt one of the existing RF amplifiers designs according to your specifications. Please contact us for additional information.

Model Number Codification

MODEL NUMBER



ERZIA

20150407_rev1.0

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